Pentacoordinate Silicon Complexes

An Unexpected, Sterically Driven, Methyl Halide Elimination in Pentacoordinate Siliconium Halide Salts: Silicon Complexes with Equatorial Nitrogen Coordination**

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Donor-stabilized silyl cation salts have recently drawn considerable attention. [1-6] Several reactions leading to such complexes [2-6] and the utility of these complexes as catalysts have been reported. [7] While dozens of previously reported pentacoordinate (as well as hexacoordinate) silicon complexes with a dimethylamino donor group (1, 2) are thermally stable, [8] we now report that certain pentacoordinate siliconium halide salts undergo a facile and quantitative elimination of a methyl halide to produce neutral pentacoordinate silicon complexes with unprecedented equatorial nitrogen coordination (Scheme 1).

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Scheme 1. Elimination of a methyl halide from bis- $(N \rightarrow Si)$ -coordinated siliconium salts **3–5** to give neutral, singly $(N \rightarrow Si)$ -coordinated complexes **7**.

tert-Butylsiliconium chlorides **3a–c** were obtained by transsilylation of tBuSiCl₃ with the corresponding N-dimethylamino-O-trimethylsilylimidates [Me₃SiOC(R)=NNMe₂] and readily converted into the siliconium halides or triflates **4–6** by treatment with Me₃SiY.^[6c]

A unique feature of the *t*Bu-substituted compounds 3–5 is that under mild heating (65°C) they quantitatively undergo methyl halide elimination to form novel, neutral pentacoordinate complexes **7** (Scheme 1).^[9] In this reaction, one of the two initially equivalent Me₂N groups loses a methyl substituent to produce a complex with one covalent and one dative N–Si bond. The products of elimination were isolated and characterized by X-ray crystal-structure analysis (Figure 1 a)^[10] and by standard methods.

The progress of the elimination reaction (at 65 °C, in CDCl₃, in a flask sealed under vacuum) was monitored by ¹H

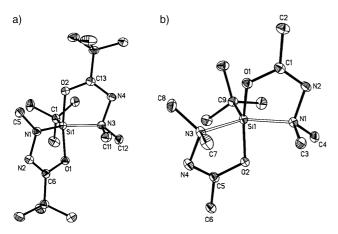


Figure 1. Crystallographic molecular structures of 7b (a) and 6a (b) at the 50% probability level. Hydrogen atoms omitted for clarity. For 6a only the cation is shown; the separate triflate anion has been omitted.

and 29 Si NMR spectroscopy, and was found to depend on the counterion: With respect to the halide the order of reactivity is I > Br > Cl (50% elimination after 85, 130, and 175 min, respectively, from **5c**, **4c**, and **3c**), whereas the siliconium triflates **6a–6c** did not react. It is thus evident that nucleophilic attack of the anion at one of the *N*-methyl groups is involved in the rate-determining step of the elimination.

The special observations made regarding the tBu complexes 3–6 can be rationalized in terms of steric bulk: a) the direct formation of 3 by transsilylation (in contrast with analogues 2, which contain X = Me, Ph, or PhCH₂ in place of the tBu group and are formed via the neutral hexacoordinate species 1) results from the difficulty in accommodating both the tBu and the halide ligands next to each other; b) likewise, steric repulsion between the adjacent tBu and Me_2N groups in 3–5, which is at least partly released by elimination, may account for the facile loss of the methyl halide. These arguments are strengthened by comparison of the crystal structures of the relevant complexes (6a, 7b, Figure 1, Table 1). [10]

Table 1: Selected bond lengths and angles for 6a and 7b.

	Si-O [Å]	Si-N [Å]	Si-C [Å]	O-Si-O [°]	N-Si-N [°]
6a	1.7240(8)	1.9397(10)	1.8964(11)	152.22(4)	133.54(4)
	1.7266(8)	1.9470(10)			
7 b	1.7844(7)	1.7265(9)	1.9115(10)	165.74(4)	121.51(4)
	1.7591 (7)	1.9496(9)			

The striking feature of the structure of the elimination product 7b is that the Me_2N donor ligand, as well as the covalent Si-N bond, occupy *equatorial* positions in the slightly distorted trigonal bipyramidal (TBP) complex. To the best of our knowledge, no equatorial coordination by a nitrogen ligand has been reported in pentacoordinate silicon complexes.^[8]

The molecular structure of **6a**, the triflate analogue of the elimination precursors **3a–5a**,^[11] was also unexpected: Even in the elimination precursor the nitrogen ligands occupy the equatorial-like and the oxygen ligands the axiallike positions, as judged from the corresponding N-Si-N (133.54°) and O-Si-O (152.22°) bond angles. This is in sharp contrast to all previously reported crystal structures for analogous siliconium salts **2** with different X ligands, in all of which the nitrogen ligands occupy essentially axial positions.^[6c]

Like the elimination itself, the uncommon N,N-diequatorial geometry in $\bf 7b$ and $\bf 6a$ must also be imposed by steric requirements: The bulky tBu ligand prefers to have the smaller oxygen ligands in its vicinity ($\sim 90^{\circ}$ bond angle) over the relatively large N-methylamino and N,N-dimethylamino groups. The latter are therefore placed at greater distances from the tBu group by opening up the bond angles ($\sim 120^{\circ}$). These substantial modifications of the crystal structures of tBu-substituted complexes are in line with the observation that only tert-butylsiliconium halide complexes undergo facile methyl halide elimination, whereas methyl- and benzylsiliconium complexes $\bf 2$ resist this reaction, and the bulkier $\bf 2b$

undergoes a much slower elimination (50 % MeI elimination after 90 h at 65 °C).

The uncommon molecular geometries found in the crystal structures of **7b** and **6a** can be viewed within a larger framework as points along a hypothetical Berry pseudorotation reaction coordinate.^[12] A single pseudorotation process is depicted schematically in Figure 2. Each point along the

Figure 2. Schematic progress along a Berry pseudorotation coordinate, with corresponding molecular structures and N-Si-N and O-Si-O angles (°). For references, see text. TBP=trigonal bipyramidal, SP=square planar.

pseudorotation coordinate has a corresponding crystal structure, and thus the entire process can be followed crystallographically, in a Burgi–Dunitz sense.^[13]

The progress along the reaction coordinate is evident from the variation in the N-Si-N and O-Si-O (or C-Si-C) angles, which determine the overall geometry. Initially the geometry corresponds to TBP1, with two *trans*-diaxial nitrogen ligands (9).^[2a] This is the common geometry for pentacoordinate

bischelates with two nitrogen donor ligands.^[8] The N-Si-N angle gradually decreases along the series, while the O-Si-O angle increases, via a distorted TBP (2a, ~65% TBP1 \rightarrow SP), ^[6c] through pure square planar (SP) geometry (8; evidenced by the N-Si-N \simeq O-Si-O angles), ^[6e] then through another distorted TBP with axiallike oxygen ligands (6a), and finally to the TBP2 geometry of 7b, which is essentially an inverted TBP in which axial and equatorial groups have exchanged their positions. Throughout this process the tBu group acts as a "pivot" for the pseudorotation.

As mentioned above, most pentacoordinate bischelates of silicon with two $N\rightarrow Si$ dative bonds have TBP1 geometry. Clearly this geometry is preferred. It is only the steric strain introduced by the tBu group in 3–5 and 7, or in the binuclear 8, that pushes the geometry towards the other end of the reaction coordinate and enables the demonstration of stable points along the entire pseudorotation coordinate. The methyl halide elimination described herein may provide a new synthetic route to MeN-Si compounds.

Experimental Section

4a-c-6a-c were obtained from 3a-c^[6c] by reaction with excess Me₃SiY in 80-97% yield. 6a: Me₃SiOSO₂CF₃ (0.777 g, 3.5 mm) was added as a solution in hexane to $3a^{[6c]}$ (0.977 g, 3.4 mm), and the mixture was stirred for 2 h at room temperature. The volatile components were removed at 0.02 mmHg, leaving 6a (1.205 g, 88%) as a white precipitate, m.p. 197-198°C, which was recrystallized for X-ray analysis from CH₂Cl₂. ¹H NMR (500 MHz, CDCl₃, 300 K): $\delta = 1.07$ (s, 9H, tBu), 2.08 (s, 6H, CMe), 3.05, 3.12 ppm (2 s, 6H, NMe₂); ¹³C NMR (125.8 MHz, CDCl₃, 300 K): $\delta = 16.9$ (CCH₃), 23.0 (Me_3C) , 29.7 $(CH_3)_3C$), 49.7, 51.8 (NMe_2) , 120.6 $(q, {}^1J = 321 \text{ Hz}, CF_3)$, 169.0 ppm (C=N); ²⁹Si NMR (99.4 MHz, CDCl₃, 300 K): δ = -61.2 ppm. **7b**: A solution of **3b** (0.804 g, 1.97 mм) in CHCl₃ (5 mL) was kept in a preevacuated flask immersed in a 90 °C bath for 6 days. The volatiles were removed at 0.02 mmHg, and the residue was recrystallized from hexane, to give 7b (0.386 g, 55%), m.p. 77-78°C. ¹H NMR (500 MHz, CDCl₃, 300 K): $\delta = 0.86$ (s, 9H, tBu-Si), 1.09 (s, 18H, tBu-C), 2.40 (s, 3H, NMe), 2.88, 3.01 ppm (2 s, 6H, NMe₂); ¹³C NMR (125.8 MHz, CDCl₃, 300 K): $\delta = 25.0$ (Me₃CSi), 27.3, 27.7, 29.3 ((CH₃)₃C), 33.9, 35.1 (Me₃CC), 36.8 (NMe), 47.8, 49.0 $(NMe_2), \ 160.9, \ 176.8 \ ppm \ \ (C=N); \ ^{29}Si \ NMR \ \ (99.4 \ MHz, \ CDCl_3,$ 300 K): $\delta = -73.1$ ppm; elemental analysis: calcd for $C_{17}H_{36}N_4O_2Si$: C 57.26, H 10.18, N 15.71. Found: C, 57.21; H, 10.29; N, 15.59. **7a** and 7c were prepared in the same way as 7b and were characterized by analogy based on their NMR spectra. 7a: 1H NMR (500 MHz, CDCl₃, 300 K): $\delta = 0.85$ (s, 9 H, tBuSi), 1.85, 1.93 (2 s, 6 H, MeC), 2.56 (s, 3 H, NMe), 3.00, 3.90 ppm (2 s, 6 H, NMe₂); ¹³C NMR (125.8 MHz, CDCl₃, 300 K): $\delta = 16.0$, 17.0 (CCH₃), 24.1 (Me₃CSi), 28.7 ((CH₃)₃C), 36.0 (NMe), 49.7, 56.9 (NMe₂), 169.1, 170.2 ppm (C=N); ²⁹Si NMR (99.4 MHz, CDCl₃, 300 K): $\delta = -71.8$ ppm. **7c**: ¹H NMR (500 MHz, $CDCl_3$, 300 K): $\delta = 1.03$ (s, 9H, tBuSi), 2.79, 3.32 (2 s, 6H, NMe₂), 3.47 (s, 3H, NMe), 7.30–8.10 ppm (m, 10H, Ph); ¹³C NMR (125.8 MHz, CDCl₃, 300 K): $\delta = 24.6$ (Me₃CSi), 28.8 ((CH₃)₃C), 36.8 (NMe), 48.4, 50.0 (NMe₂), 124.9–132.4 (Ph), 152.8, 166.1 ppm (C=N); ²⁹Si NMR (99.4 MHz, CDCl₃, 300 K): $\delta = -71.7$ ppm.

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